

# High-Current Over-voltage Protectors

## with Adjustable OVLO

### General Description

ET9553M can disconnect the systems from its output pin(OUT) in case wrong input operating conditions are detected. The input voltage can be up to 28V. The internal overvoltage threshold (OVLO) is 10V, and also can be adjusted by external resistors. ET9553M has internal Thermal-Shutdown Protection function.

The device is packaged in advanced full-Green compliant Wafer Level Chip Scale Packaging (WLCSP12).

### Features

- 4.8A Continuous Current Capability
- Typical  $R_{ON}$ : 35m $\Omega$  N-Channel MOSFET
- $V_{IN}$  Operating Range: 2.5V to 28V
- Overvoltage Lockout:  $V_{OVLO}=10V(TYP)$
- Overvoltage-Protection Response Time: 50ns(TYP)
- OVLO Threshold Range: +4V to +24V
- Startup Debounce Time:21ms(TYP)
- Internal Thermal-Shutdown Protection
- Surge immunity to  $\pm 100V$
- ESD Protected(HBM) to  $\pm 4KV$
- Pat No. and Package

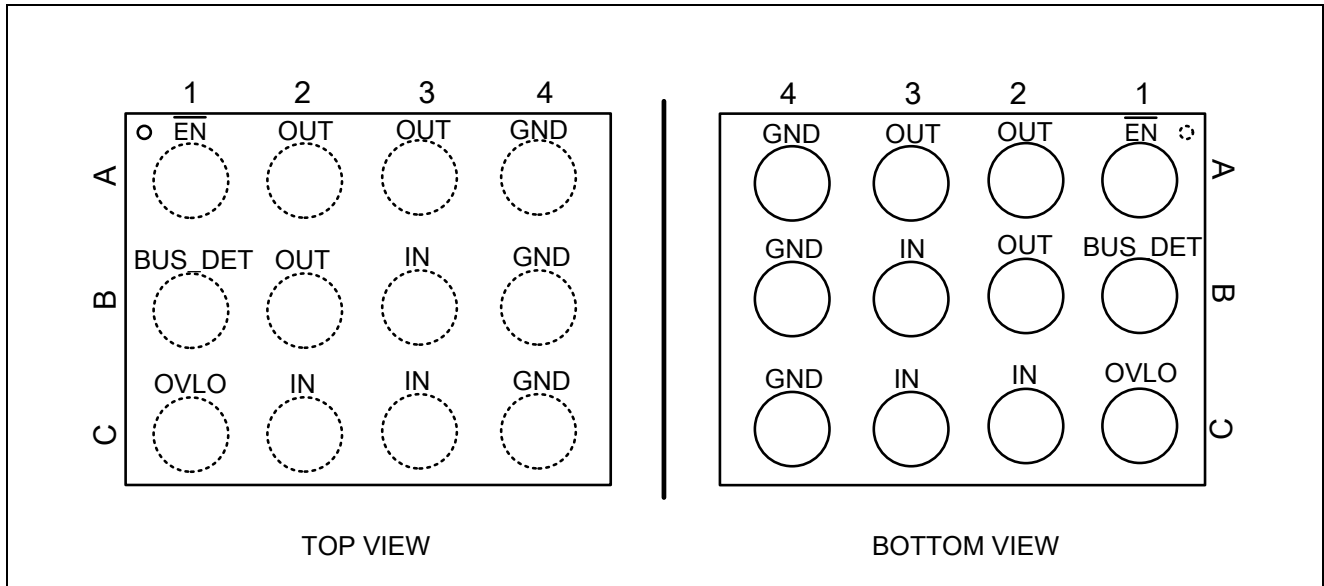
Part No.	Package
ET9553M	WLCSP12 (1.58mm $\times$ 1.18mm, ball pitch=0.4mm)

### Application

- Smartphones, Tablet PC
- HDD, Storage and Solid State Memory Devices
- Portable Media Devices, Laptop & MID
- SLR Digital Cameras
- GPS and Navigation Equipment
- Industrial Handheld and Enterprise Equipment

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## Pin Configuration

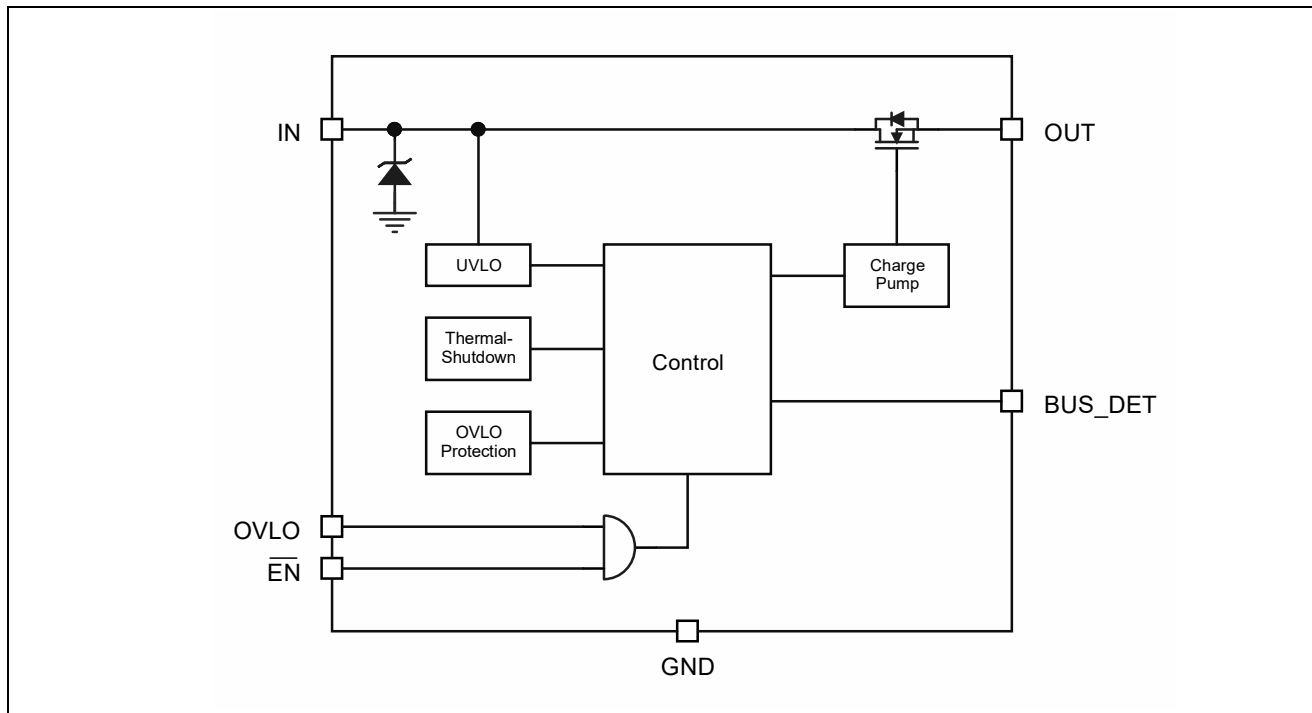


## Pin Function

Pin	Name	Description
A1	EN	Device Enable. Active low.
A2,A3,B2	OUT	Output Voltage. Output of internal switch. Connect OUT pins together for proper operation.
A4,B4,C4	GND	Ground. Connect GND pins together for proper operation.
B1	BUS_DET	Regulation output of VBUS.
B3,C2,C3	IN	Voltage Input. Connect IN pins together for proper operation.
C1	OVLO	External OVLO Adjustment. Connect OVLO to GND when using the internal threshold. Connect a resistor-divider to OVLO to set a different OVLO threshold; this external resistor-divider is completely independent of the internal threshold.

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## Block Diagram



## Functional Description

The OVP switch with overvoltage protection feature a low 35mΩ(TYP) on-resistance( $R_{ON}$ ) internal FET and protect low-voltage systems against voltage faults up to 28V<sub>DC</sub>. If  $\overline{EN}$  is in the logic low state, when the input voltage( $V_{IN}$ ) exceeds 10V, the internal FET is quickly turned off to prevent damage to the protected downstream components. If  $\overline{EN}$  is in the logic high state. The ET9553M will disables the protect low-voltage system.

### Over-voltage Protection

When input (OVLO) is set lower than 0.2V. The overvoltage protection threshold is 10V.

The overvoltage protection threshold can also be adjusted by external resistors when input (OVLO) is set higher than 0.3V.

$$V_{IN\_OVLO} = V_{OVLO\_TH} \times (1+R1/R2)$$

**Note:**  $V_{OVLO\_TH} = 1.2V(TYP)$

### Thermal Shutdown

The internal FET turns off when the junction temperature exceeds +150°C (TYP). The device exits thermal shutdown after the junction temperature cools by 20°C (TYP).

### USB OTG Operation

If  $V_{IN}=0V$  and OUT is supplied by OTG voltage, the body diode of the OVP switch conducts current from OUT to IN and the voltage drop from OUT to IN is approximately 0.7V. When place  $\overline{EN}$  pin in the logic low state and  $V_{IN}>V_{UVLO}$ , internal charge pump begins to open the OVP switch after debounce time. After switch is fully on, current is supplied through switch channel and the voltage drop from OUT to IN is minimum. When place

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$\overline{\text{EN}}$  pin in the high state, the OVP switch will not turn ON unless  $\overline{\text{EN}}$  pin is pulled LOW, the high forward voltage drop of 0.7V and consequent high power dissipation will remain. It is highly recommended to place  $\overline{\text{EN}}$  pin in the logic low state in all OTG applications.

Please note in OTG mode, under no circumstance should any load, or any voltage be connected to BUS\_DET.

## Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into load capacitor or short-circuit, a capacitor 1 $\mu$ F or larger must be placed between the IN and GND pins.

## Output Capacitor

A 1 $\mu$ F or larger capacitor should be placed between the OUT and GND pins.

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameters		Min	Max	Unit
V <sub>IN</sub>	VIN to GND		-2.0 <sup>(1)</sup>	29	V
V <sub>OUT</sub>	VOUT to GND		-0.3	28	V
V <sub>OVLO</sub>	OVLO to GND		-0.3	7	V
V <sub>/EN</sub>	$\overline{\text{EN}}$ to GND		-0.3	7	V
V <sub>BUS_DET</sub>	BUS_DET to GND		-0.3	10	V
I <sub>SW1</sub>	Maximum Continuous Current of switch IN-OUT			4.8	A
I <sub>SW2</sub>	Maximum Peak Current of switch IN-OUT(10ms)			8	A
P <sub>D</sub>	Power Dissipation at T <sub>A</sub> = +25°C			1.4	W
T <sub>STG</sub>	Storage Junction Temperature		-65	+150	°C
T <sub>A</sub>	Operating Temperature Range		-40	+85	°C
T <sub>SOLD</sub>	Soldering Temperature (reflow).			+260	°C
T <sub>J</sub>	Max Junction Temperature			+150	°C
ESD	Electrostatic Discharge Capability	IEC 61000-4-2	Air Discharge	15.0	kV
		System Level ESD	Contact Discharge	8.0	
		Human Body Model, JEDEC JS-001-2012	All Pins	>4.0	
		Charged Device Model, JESD22-C101	All Pins	>1.5	
Surge		IEC 61000-4-5, Surge Protection	VBUS	±100	V

**Note1:** Pulsed, 50ms maximum non-repetitive.

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## Electrical Characteristics

Unless otherwise noted,  $V_{IN}=2.5V$  to  $28V$ ,  $T_A=-40^{\circ}C$  to  $85^{\circ}C$ , Typical values are at  $V_{IN}=5V$ ,  $I_{IN}\leq 2A$ ,  $C_{IN}=1\mu F$  and  $T_A=25^{\circ}C$ .

Symbol	Parameters	Conditions	Min	Typ	Max	Unit
TVS Characteristics						
$V_{BR}$	Reverse Breakdown Voltage	$I_T=10mA$ , $T_A=25^{\circ}C$	29	32	36	V
$I_{PP}$	Peak Pulse Current <sup>(2)</sup>	$t_p=8/20\mu s(+100V)$ , $T_A=25^{\circ}C$	25	32.5	44	A
$V_C$	Clamping Voltage <sup>(2)</sup>	$I_{PP}=32.5A$ , $t_p=8/20\mu s$ , $T_A=25^{\circ}C$	22	35	45	V
$I_{PP\_NEG}$	Reverse Peak Pulse Current <sup>(2)</sup>	$t_p=8/20\mu s(-100V\text{ surge})$ , $T_A=25^{\circ}C$	-40	-48.5	-55	A
$V_{C\_NEG}$	Reverse Clamping Voltage <sup>(2)</sup>	$I_{PP}=-48.5A$ , $t_p=8/20\mu s$ , $T_A=25^{\circ}C$	-1	-3	-6	V
$V_F$	Forward Voltage	$I_F=10mA$ , $T_A=25^{\circ}C$	0.2	0.6	0.9	V
Basic Operation						
$V_{IN}$	Input Voltage		2.5		28	V
$I_{IN}$	$V_{IN}$ Quiescent Current	$V_{IN}=5V$ , $V_{EN}=0V$ , OUT floating	110	150	220	$\mu A$
$I_{IN\_OVLO}$	OVLO Supply Current	$V_{IN}=12V$ , $V_{EN}=0V$ , OUT floating	150	190	250	$\mu A$
$R_{ON}$	On-Resistance of Switch IN-OUT	$V_{IN}=5.0V$ , $I_{OUT}=1A$ , $T_A=25^{\circ}C$	25	35	53	m $\Omega$
$V_{OVLO}$	Overvoltage Protect of $V_{IN}$	$V_{IN}$ Rising	9.8	10	10.2	V
	Overvoltage Protect hysteresis of $V_{IN}$		0.15	0.25	0.35	V
	Adjustable OVLO Threshold Range		4		24	V
$V_{OVLO\_TH}$	OVLO Set Threshold		1.18	1.2	1.22	V
$V_{OVLO\_SELE\_CT}$	External OVLO Select Threshold		0.2		0.3	V
$V_{DET1}$	Regulation Output of BUS_DET	$V_{IN}=5V$ , $V_{EN}=0V$ , $I_{DET}=1mA$ and $C_{BUS\_DET}=1\mu F$	4.8			V
$V_{DET2}$	Regulation Output of BUS_DET	$V_{IN}=9V$ , $V_{EN}=0V$ , $I_{DET}=10mA$ and $C_{BUS\_DET}=1\mu F$	6	6.7	7.5	V
$V_{UVLO}$	Undervoltage Protect of $V_{IN}$	$V_{IN}$ Rising	1.7	2.0	2.5	V
		$V_{IN}$ Falling	1.5	1.8	2.3	V
$I_{OVLO}$	OVLO Input Leakage Current	$V_{OVLO}=V_{OVLO\_TH}$	-100		100	nA
$V_{IH}$	$\overline{EN}$ Input Logic High Voltage	$V_{IN}=2.5V$ to $28V$	1.4			V

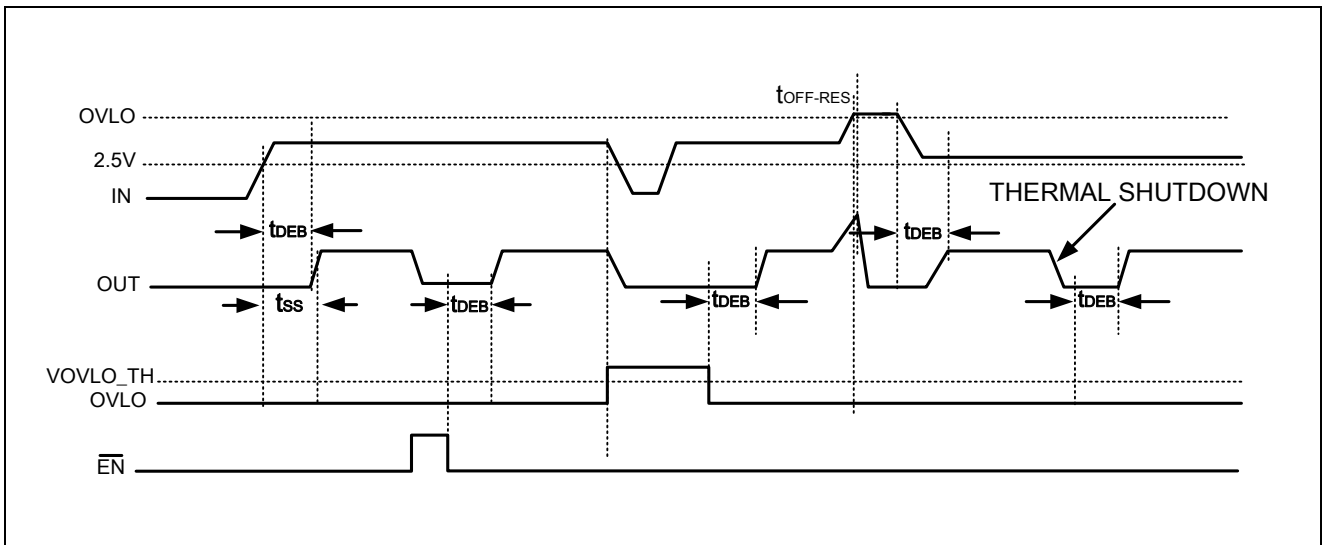
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## Electrical Characteristics (Continued)

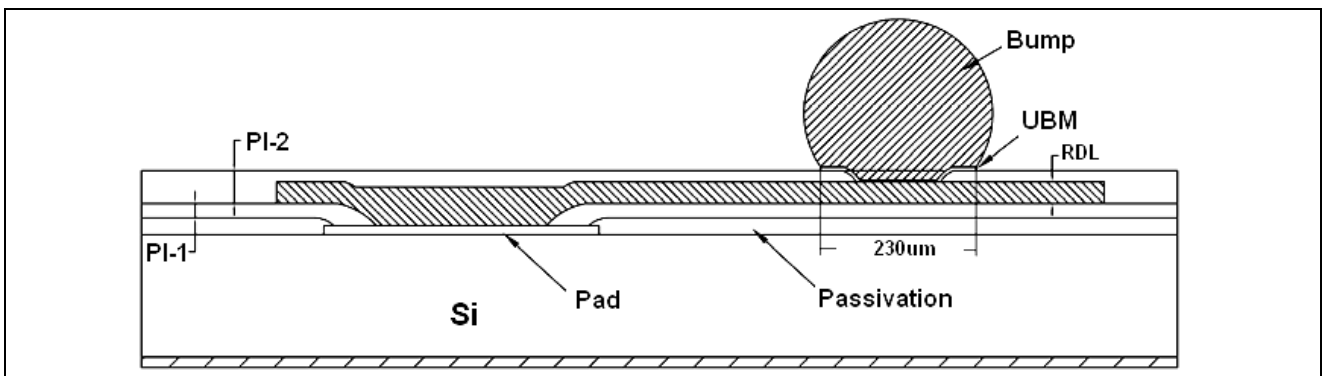
Symbol	Parameters	Conditions	Min	Typ	Max	Unit
$V_{IL}$	$\overline{EN}$ Input Logic Low Voltage	$V_{IN}=2.5V$ to $28V$			0.3	V
$T_{SHDN}$	Thermal Shutdown <sup>(2)</sup>			150		°C
$T_{SHDN\_HYS}$	Thermal-Shutdown Hysteresis <sup>(2)</sup>			20		°C
Dynamic Characteristics: see figure						
$t_{DEB}$	Debounce Time	Time from $V_{UVLO}<V_{IN}<V_{OVLO}$ to $V_{OUT}=10\%$ of $V_{IN}$		21	32	ms
$t_{SS}$	Soft-Start time	Time from $V_{UVLO}<V_{IN}<V_{OVLO}$ to $V_{OUT}=90\%$ of $V_{IN}$		23	35	ms
$t_{OFF\_RES}$	Switch Turn-off Response Time <sup>(2)</sup>	$R_L=100\Omega$ , No $C_L$ , $V_{IN} > V_{OVLO}$ to $V_{OUT}$ stop rising		50	80	ns

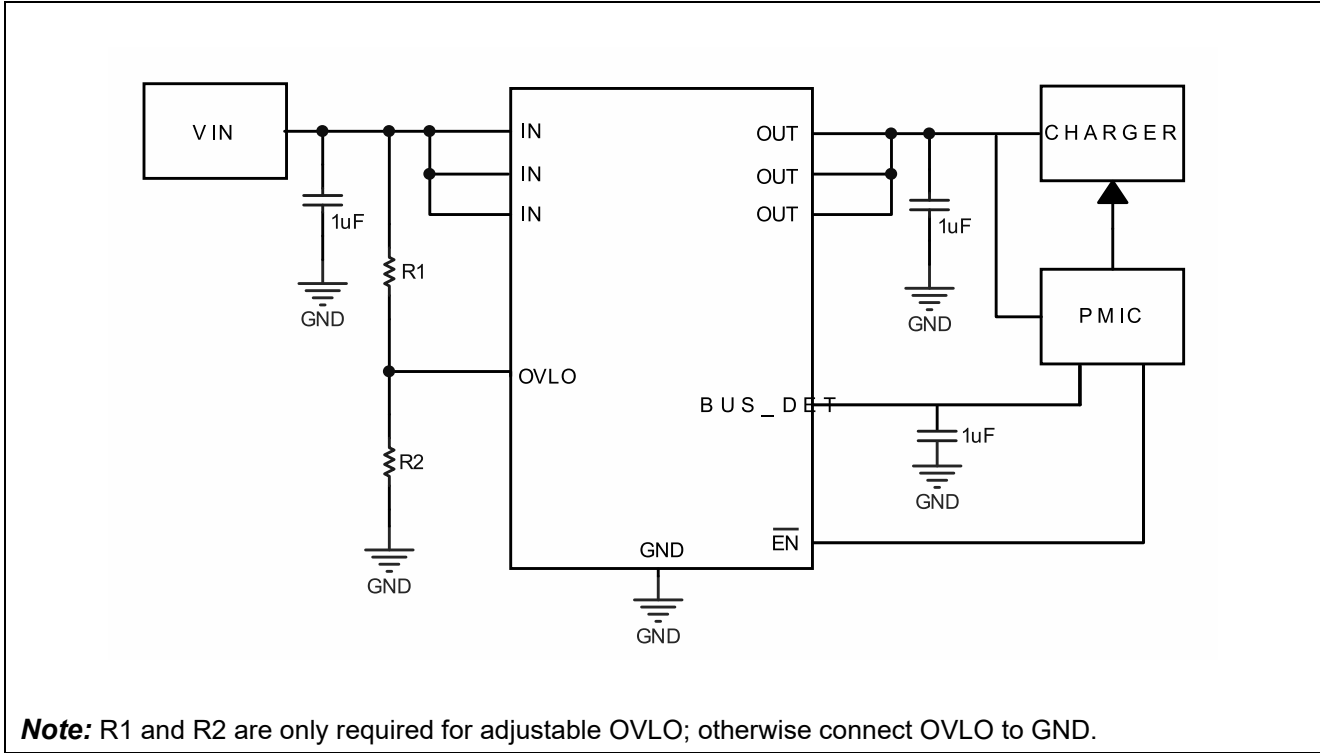
**Note2:** This parameter is guaranteed by design and characterization.

## Timing Waveform



## UBM Structure



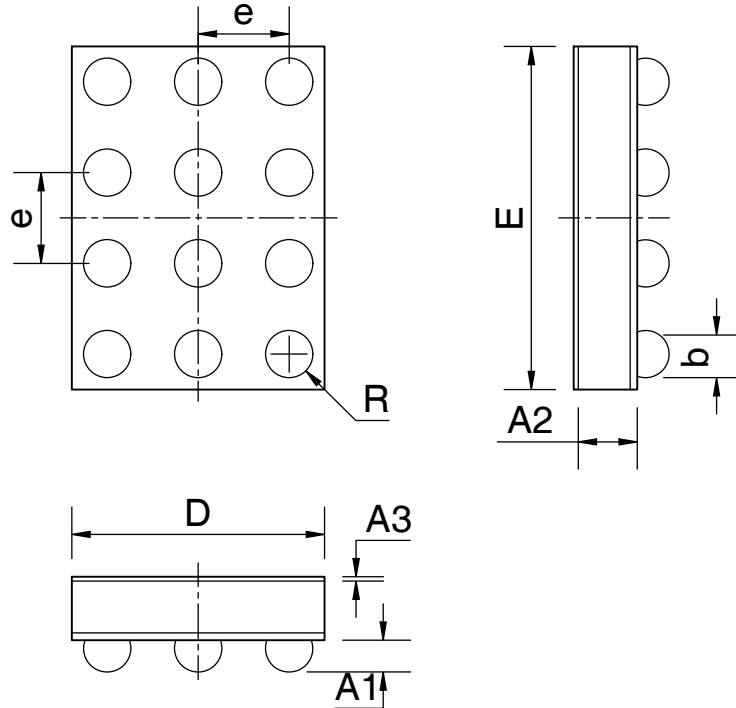


\*: This application circuit is for reference only.

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## Package Dimension

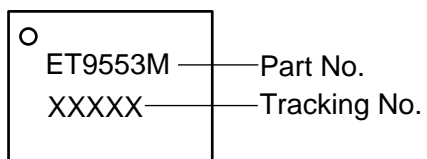
WLCSP12



COMMON DIMENSIONS  
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A1	0.18	0.20	0.22
A2	0.34	0.35	0.36
A3	0.018	0.025	0.032
b	0.24	0.27	0.30
D	1.13	1.18	1.23
E	1.53	1.58	1.63
e	0.40BSC		
R	0.24	0.27	0.30

## Marking





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**Revision History and Checking Table**

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2019-05-30	Original Version	Wum	Wum	LiuJy
1.1	2019-06-10	Change I <sub>PP</sub> max to 44A	Wum	Wum	LiuJy
1.2	2022-12-15	Update Typeset	Liwc Shib	Wum	LiuJy